1ch Gate Driver Providing Galvanic Isolation 2500Vrms Isolation Voltage

BM60051FV-C

General Description

The BM60051FV-C is a gate driver with an isolation voltage of 2500Vrms, I/O delay time of 260ns, minimum input pulse width of 180ns, and incorporates the fault signal output function, under voltage lockout (UVLO) function, short circuit protection (SCP) function, active miller clamping function, temperature monitoring function, switching controller function and output state feedback function.

Features

- Fault signal output function
- Under voltage lockout function
- Short circuit protection function
- Active Miller Clamping
- Temperature monitor
- Switching controller
- Output State Feedback Function
- AEC-Q100 Qualified

Applications

- Automotive isolated IGBT/MOSFET inverter gate drive.
- Automotive DC-DC converter.
- Industrial inverters system.
- UPS system.

Key Specifications

- Isolation Voltage: 2500 [Vrms] (Max)
- Maximum Gate Drive Voltage: 24 [V] (Max)
- I/O Delay Time: 260 [ns] (Max)
- Minimum Input Pulse Width: 180 [ns] (Max)

Packages

	W(Typ) x D(Typ) x H(Max)
SSOP-B28W	9.2mm x 10.4mm x 2.4mm

TBD

Typical Application Circuit

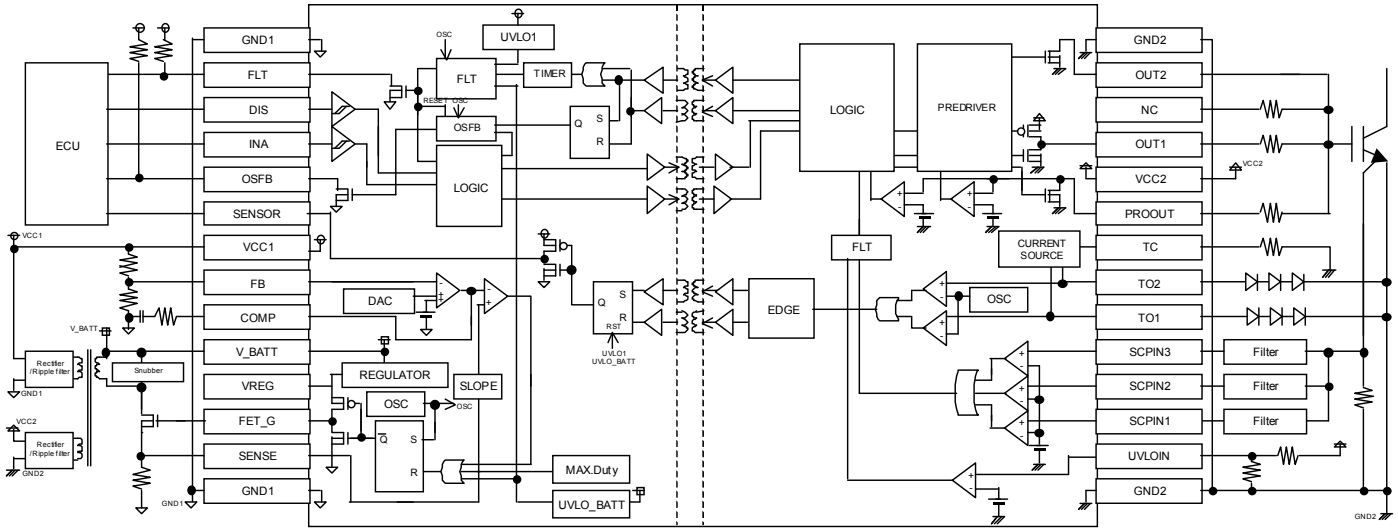


Figure 1. Typical Application Circuit

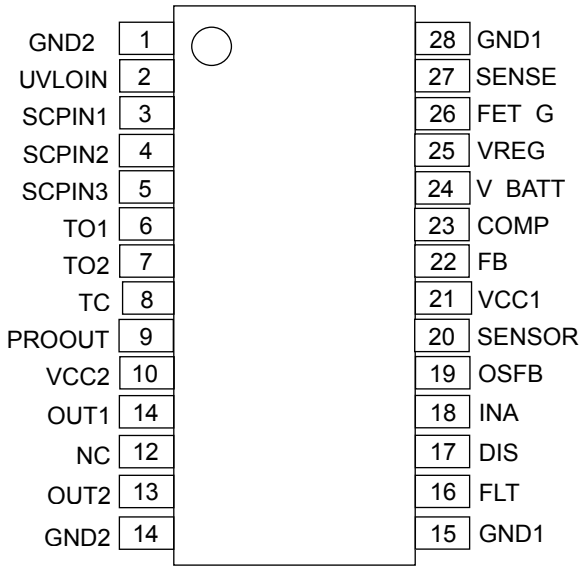
Recommended Range Of External Constants

Pin Name	Symbol	Recommended Value			Unit
		Min	Typ	Max	
TC(Note1)	R_{TC}	1.25	-	50	kΩ
TC(Note2)	R_{TC}	0.1	1	10	MΩ
VBATT	C_{VBATT}	3	-	-	μF
VCC1	C_{VCC1}	0.2	-	-	μF
VCC2	C_{VCC2}	0.4	-	-	μF
VREG	C_{VREG}	0.1	1	10	μF

(Note1) Use Temperature monitor
(Note2) No use Temperature monitor

Pin Configuration

(TOP VIEW)



Pin Descriptions

Pin No.	Pin Name	Function
1	GND2	Output-side ground pin
2	UVLOIN	Output-side UVLO setting pin
3	SCPIN1	Short circuit current detection pin 1
4	SCPIN2	Short circuit current detection pin 2
5	SCPIN3	Short circuit current detection pin 3
6	TO1	Constant current output pin / sensor voltage input pin 1
7	TO2	Constant current output pin / sensor voltage input pin 2
8	TC	Constant current setting resistor connection pin
9	PROOUT	Soft turn-OFF pin /Gate voltage input pin
10	VCC2	Output-side power supply pin
11	OUT1	Output pin
12	NC	No connect
13	OUT2	Output pin for Miller Clamp
14	GND2	Output-side ground pin
15	GND1	Input-side ground pin
16	FLT	Fault output pin
17	DIS	Input enabling signal input pin
18	INA	Control input pin
19	OSFB	Output state feedback output pin
20	SENSOR	Temperature information output pin
21	VCC1	Input-side power supply pin
22	FB	Error amplifier inverting input pin for switching controller
23	COMP	Error amplifier output pin for switching controller
24	V_BATT	Main power supply pin
25	VREG	Power supply pin for driving MOS FET for switching controller
26	FET_G	MOS FET control pin for switching controller
27	SENSE	Current feedback resistor connection pin for switching controller
28	GND1	Input-side ground pin

Absolute Maximum Ratings

Parameter	Symbol	Limit	Unit
Main Power Supply Voltage	$V_{BATTMAX}$	-0.3 to+40.0 (Note 1)	V
Input-Side Control Block Supply Voltage	V_{CC1MAX}	-0.3 to +7.0 (Note 1)	V
Output-Side Supply Voltage	V_{CC2MAX}	-0.3 to +30.0 (Note 2)	V
INA, DIS Pin Input Voltage	V_{INMAX}	-0.3 to +V_{CC1}+0.3V or 7.0V (Note 1)	V
FLT, OSFB Pin Input Voltage	V_{FLTMAX}	-0.3 to 7.0V (Note 1)	V
FLT Pin, OSFB Pin Output Current	I_{FLT}	10	mA
SENSOR Pin Output Current	I_{SENSOR}	10	mA
FB Pin Input Voltage	V_{FBMAX}	-0.3 to +V_{CC1}+0.3V or 7.0V (Note 1)	V
FED_G Pin Output Current (Peak5µs)	I_{FET_GPEAK}	1000	mA
SCPIN1 Pin, SCPIN2 Pin, SCPIN3 Pin Input Voltage	$V_{SCPINMAX}$	-0.3 to +6.0 (Note 2)	V
UVLOIN Pin Input Voltage	$V_{UVLOINMAX}$	-0.3 to V_{CC2}+0.3 (Note 2)	V
TO1 Pin, To2 Pin Input Voltage	V_{TOMAX}	-0.3 to V_{CC2}+0.3 (Note 2)	V
TO1 Pin, TO2 Pin Output Current	I_{TOMAX}	8	mA
OUT1 Pin Output Current (Peak5µs)	$I_{OUT1PEAK}$	5000 (Note 3)	mA
OUT2 Pin Output Current (Peak5µs)	$I_{OUT2PEAK}$	5000 (Note 3)	mA
PROOUT Pin Output Current (Peak5µs)	$I_{PROOUTPEAK5}$	2500 (Note 3)	mA
PROOUT Pin Output Current (Peak10µs)	$I_{PROOUTPEAK10}$	1000 (Note 3)	mA
Power Dissipation	Pd	TBD (Note 4)	W
Operating Temperature Range	Topr	-40 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Junction Temperature	Tjmax	+150	°C

(Note 1) Relative to GND1
(Note 2) Relative to GND2
(Note 3) Should not exceed Pd and Tj=150°C
(Note 4) TBD (Derate above Ta=25°C at a rate of xxxmW/°C. Mounted on a glass epoxy of 70 mm × 70 mm × 1.6 mm.)
Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Units
Main Power Supply Voltage	V_{BATT} (Note 5)	4.5	24.0	V
Input-side Control Block Supply Voltage	V_{CC1} (Note 5)	4.5	5.5	V
Output-side Supply Voltage	V_{CC2} (Note 6)	(8)	24	V
Output side UVLO voltage	V_{UV2TH} (Note 6)	6	-	V

(Note 5) GND1 reference
(Note 6) GND2 reference

Insulation Related Characteristics

Parameter	Symbol	Characteristic	Unit
Insulation Resistance (V_{IO}=500V)	R_S	$>10^9$	Ω
Insulation Withstand Voltage / 1min	V_{ISO}	2500	Vrms
Insulation Test Voltage / 1sec	V_{ISO}	3000	Vrms

Electrical Characteristics

(Unless otherwise specified Ta=-40°C to125°C, V_{BATT}=5V to 24V, V_{CC1}=4.5V to 5.5V, V_{CC2}=8V to 24V)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
General						
Main Power Supply Circuit Current 1	I_{BATT1}	0.37	0.84	1.47	mA	FET_G Pin switching operating
Main Power Supply Circuit Current 2	I_{BATT2}	0.34	0.77	1.35	mA	FET_G Pin No Switching
Input Side Circuit Current 1	I_{CC11}	0.13	0.31	0.49	mA	OUT=L
Input Side Circuit Current 2	I_{CC12}	0.13	0.31	0.49	mA	OUT=H
Input Side Circuit Current 3	I_{CC13}	0.25	0.42	0.59	mA	INA =10kHZ, Duty=50%
Input Side Circuit Current 4	I_{CC14}	0.31	0.53	0.74	mA	INA =20kHZ, Duty=50%
Output Side Circuit Current	I_{CC2}	2.7	4.7	7.1	mA	
Switching Power Supply Controller						
FET_G Output Voltage H1	V_{FETGH1}	4.5	5.0	5.5	V	I_{OUT}=0A(open)
FET_G Output Voltage H2	V_{FETGH2}	4.0	4.5	-	V	V_BATT=4.5V I_{OUT}=0A(open)
FET_G Output Voltage L	V_{FETGL}	0	-	0.3	V	I_{OUT}=0A(open)
FET_G ON-Resistance (Source-side)	R_{ONGH}	3	6	12	Ω	10mA
FET_G ON-Resistance (Sink-side)	R_{ONGL}	0.3	0.6	1.3	Ω	10mA
Oscillation Frequency	f_{OSC_SW}	80	100	120	kHz	
Soft-start Time	t_{SS}	-	-	50	ms	
FB Pin Threshold Voltage	V_{FB}	1.47	1.50	1.53	V	
FB Pin Input Current	I_{FB}	-0.8	0	+0.8	μA	
COMP Pin Sink Current	$I_{COMPSINK}$	-160	-80	-40	μA	
COMP Pin Source Current	$I_{COMPSOURCE}$	40	80	160	μA	
V_BATT UVLO OFF Voltage	$V_{UVLOBATTH}$	4.05	4.25	4.45	V	
V_BATT UVLO ON Voltage	$V_{UVLOBATTL}$	3.95	4.15	4.35	V	
Maximum ON DUTY	D_{ONMAX}	75	85	95	%	
Logic Block						
Logic High Level Input Voltage	V_{INH}	$0.7\times V_{CC1}$	-	V_{CC1}	V	INA、DIS
Logic Low Level Input Voltage	V_{INL}	0	-	$0.3\times V_{CC1}$	V	INA、DIS
Logic Pull-Down Resistance	R_{IND}	25	50	100	kΩ	INA
Logic Pull-Up Resistance	R_{INU}	25	50	100	kΩ	DIS
Logic Input Filtering Time	t_{INFIL}	80	130	180	ns	INA
DIS Input Filtering Time	T_{DISFIL}	4	10	20	μs	
DIS Input Delay Time	t_{DDIS}	4	10	20	μs	
Output						
OUT1 ON-Resistance (Source-side)	R_{ONH}	0.2	0.55	1.3	Ω	I_{OUT}=40mA
OUT1 ON-Resistance (Sink-side)	R_{ONL}	0.2	0.55	1.3	Ω	I_{OUT}=40mA
OUT1 Maximum Current	I_{OUTMAX}	5.0	-	-	A	V_{CC2}=15V Guaranteed by design
PROOUT ON-Resistance	R_{ONPRO}	0.4	0.9	2.0	Ω	I_{PROOUT}=40MA
Turn ON time	t_{PON}	140	200	260	ns	
Turn OFF time	t_{POFF}	140	200	260	ns	
Propagation Distortion	t_{PDIST}	-60	0	+60	ns	t_{POFF} - t_{PON}
Rise Time	t_{RISE}	-	30	50	ns	Load=1nF
Fall Time	t_{FALL}	-	30	50	ns	Load=1nF
OUT2 ON-Resistance	R_{ON2}	0.4	0.9	2.0	Ω	I_{OUT}=40mA
OUT2 ON Threshold Voltage	V_{OUT2ON}	1.8	2.0	2.2	V	
OUT2 Output Delay Time	t_{OUT2ON}	-	15	50	ns	
Common Mode Transient Immunity	CM	100	-	-	kV/μs	Design assurance

Electrical Characteristics - continued

(Unless otherwise specified Ta=-40°C to125°C, V_{BATT}=5V to 24V, V_{CC1}=4.5V to 5.5V, V_{CC2}=8V to 24V)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Temperature Monitor						
TC Pin Voltage	V_{TC}	0.975	1.000	1.025	V	
TOx Pin Output Current	I_{TO}	0.97	1.00	1.03	mA	R_{TC}=10kΩ
SENSOR Output Frequency	f_{OSC_TO}	8	10	14	kHz	
SENSOR Output Duty1	$D_{SENSOR1}$	87	90	93	%	V_{TOx}=1.35V
SENSOR Output Duty2	$D_{SENSOR2}$	47	50.0	53	%	V_{TOx}=2.59V
SENSOR Output Duty3	$D_{SENSOR3}$	5	10	15	%	V_{TOx}=3.84V
TOx Pin Disconnect Detection Voltage	V_{TOH}	7	8	9	V	
SENSOR ON Resistance (Source-side)	$R_{SENSORH}$	-	60	160	Ω	I_{SENSOR}=5mA
SENSOR ON Resistance (Sink-side)	$R_{SENSORL}$	-	60	160	Ω	I_{SENSOR}=5mA
Protection Functions						
Input-side UVLO OFF Voltage	V_{UVLO1H}	4.05	4.25	4.45	V	
Input-side UVLO ON Voltage	V_{UVLO1L}	3.95	4.15	4.35	V	
Input-side UVLO Filtering Time	$t_{UVLO1FIL}$	2	10	30	µs	
Input-side UVLO Delay Time (OUT)	$t_{DUVLO1OUT}$	2	10	30	µs	
Input-side UVLO Delay Time (FLT)	$t_{DUVLO1FLT}$	2	10	30	µs	
Output-side UVLO OFF Threshold Voltage	V_{UVLO2H}	0.95	1.00	1.05	V	
Output-side UVLO ON Threshold Voltage	V_{UVLO2L}	0.85	0.90	0.95	V	
Output-side UVLO Filtering Time	$t_{UVLO2FIL}$	2	10	30	µs	
Output-side UVLO Delay Time (OUT)	$t_{DUVLO2OUT}$	2	10	30	µs	
Output-side UVLO Delay Time (FLT)	$t_{DUVLO2FLT}$	3	-	65	µs	
Short Current Detection Voltage	V_{SCDET}	0.67	0.70	0.73	V	
Short Current Detection Filtering Time	t_{SCPFIL}	0.15	0.30	0.45	µs	
Short Current Detection Delay time (OUT)	$t_{DSCPOUT}$	0.16	0.33	0.50	µs	OUT1=30kΩ Pull down
Short Current Detection Delay Time (PROOUT)	$t_{DSCPPRO}$	0.17	0.35	0.53	µs	PROOUT=30kΩ Pull up
Short Current Detection Delay Time (FLT)	$t_{DSCPFLT}$	1	-	35	µs	
Soft Turn OFF Release Time	t_{SCPOFF}	30	-	110	µs	OUT1=30kΩ Pull up
FLT Output ON-Resistance	R_{FLTL}	-	30	80	Ω	I_{FLT}=5mA
Fault Output Holding Time	t_{FLTRLS}	20	40	60	ms	
Gate State H Detection Threshold Voltage	V_{OSFBH}	4.5	5.0	5.5	V	
Gate State L Detection Threshold Voltage	V_{OSFBL}	4.0	4.5	5.0	V	
OSFB Output Filtering Time	$t_{OSFBFIL}$	1.5	2.0	2.5	µs	
OSFB Output ON-Resistance	R_{OSFB}	-	30	80	Ω	I_{OSFB}=5mA
OSFB Output Holding Time	$t_{OSFBRLS}$	20	40	60	ms	

Description of Pins and Cautions on Layout of Board

1. V_BATT (Main power supply pin)
   This is the main power supply pin. Connect a bypass capacitor between V_BATT and GND1 in order to suppress voltage variations. Be sure to apply a power supply even when the switching power supply is not used, since the internal reference voltage of the input side chip is generated from this power supply.

2. VCC1 (Input-side power supply pin)
   The VCC1 pin is a power supply pin on the input side. To suppress voltage fluctuations due to the driving current of the internal transformer, connect a bypass capacitor between the VCC1 and the GND1 pins.

3. GND1 (Input-side ground pin)
   The GND1 pin is a ground pin on the input side.

4. VCC2 (Output-side positive power supply pin)
   The VCC2 pin is a positive power supply pin on the output side. To reduce voltage fluctuations due to the driving current of the internal transformer and output current, connect a bypass capacitor between the VCC2 and the GND2 pins.

5. GND2 (Output-side ground pin)
   The GND2 pin is a ground pin on the output side. Connect the GND2 pin to the emitter / source of output device.

6. INA, DIS (Control input pin, input enabling signal input pin)
   They are pins for deciding the output logic.

DIS	INA	OUT1
H	X	L
L	L	L
L	H	H

X: Don't care

7. FLT (Fault output pin)
   The FLT pin is an open drain pin that outputs a fault signal when a fault occurs (i.e., when the under voltage lockout function (UVLO) or short circuit protection function (SCP) is activated).

State	FLT
While in normal operation	Hi-Z
When a Fault occurs (UVLO / SCP)	L

8. OSFB (Output pin for monitoring gate condition)
   This is an open drain pin which compares gate logic of the output element monitored with PROOUT pin and DIS/INA pin input logic, and outputs L when they disaccord.

Status	DIS	INA	PROOUT(input)	OSFB
Normal operation	H	X	H	L
	H	X	L	Hi-Z
	L	L	H	L
	L	L	L	Hi-Z
	L	H	H	Hi-Z
	L	H	L	L
Fault	X	X	X	Hi-Z

X: Don't care

9. SENSOR (Temperature information output pin)
   This is a pin which outputs the voltage of either TO1 or TO2, whichever is lower, converted to Duty cycle.

10. FB (Error amplifier inverting input pin for switching controller)
    This is a voltage feedback pin of the switching controller. Connect it to VCC1 when the switching controller is not used.

11. COMP (Error amplifier output pin for switching controller)
    This is the gain control pin of the switching controller. Connect a phase compensation capacitor and resistor. When the switching controller is not used, connect it to GND1.

12. VREG (Power supply pin for the driving MOS FET of the switching controller)
    This is the power supply pin for the driving MOSFET of the switching controller transformer drive. Be sure to connect a capacitor between VREG and GND1 even when the switching controller is not used, in order to prevent oscillation and suppress voltage variation due to FET_G output current.

Description of Pins and Cautions on Layout of Board – continued

13. FET_G (MOS FET control pin for switching controller)
    This is a MOSFET control pin for the switching controller transformer drive. Leave it unconnected when the switching controller is not used.

14. SENSE (Connection to the current feedback resistor of the switching controller)
    This is a pin connected to the resistor of the switching controller current feedback. Connect it to VCC1 when switching controller is not used.

15. OUT(Output pin)
    The OUT pin is a gate driving pin.

16. OUT2 (Miller clamp pin)
    This is the miller clamp pin for preventing a rise of gate voltage due to miller current of output element connected to OUT1. OUT2 should be unconnected when miller clamp function is not used.

17. PROOUT (Soft turn-OFF pin)
    This is a pin for soft turn-OFF of output pin when short-circuit protection is in action. It also functions as a pin for monitoring gate voltage for miller clamp function and output state feedback function.

18. SCPIN1, SCPIN2, SCPIN3 (Short circuit current detection pin)
    The SCPIN pin is the pin used to detect current for short circuit protection. When the SCPIN pin voltage exceeds the voltage set with the V_{SCDET} parameter, the SCP function will be activated, this will make the IC function in an open state. To avoid such trouble, connect a resistor between the SCPIN and the GND2 or short the SCPIN pin to GND2 when the SCP function is not used.

19. TC (Resistor connection pin for setting constant current source output)
    The TC pin is a resistor connection pin for setting the constant current output. If an arbitrary resistance value is connected between TC and GND2, it is possible to set the constant current value output from TO.

20. TO1, TO2 (Constant current output / sensor voltage input pin)
    The TOx pin is a constant current output / voltage input pin. It can be used as a sensor input by connecting an element with arbitrary impedance between TOx pin and GND. If the voltage of TO pin falls below the setting voltage input in TTH pin, this IC turns OFF the output and sets FLT output to L status. Furthermore, the TOx pin disconnect detection function is built-in.

21. UVLOIN (Output-side UVLO setting input pin)
    The UVLOIN pin is a pin for deciding UVLO setting value of VCC2. The threshold value of UVLO can be set by dividing the resistance voltage of VCC2 and inputting such value.

Description of Functions and Examples of Constant Setting

1. Fault status output

This function is used to output a fault signal from the FLT pin when a fault occurs (i.e., when the under voltage lockout function (UVLO) or short circuit protection function (SCP) is activated) and hold the fault signal until fault output holding time (t_{FLTRLS}) is completed.

Status	FLT pin
Normal	Hi-Z
Fault occurs	L

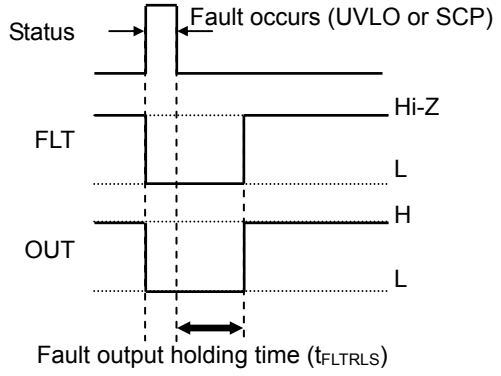


Figure 2. Fault Status Output Timing Chart

2. Under voltage Lockout (UVLO) function

The BM60051FV-C incorporates the under voltage lockout (UVLO) function on V_BATT, VCC1 and VCC2. When the power supply voltage drops to the UVLO ON voltage, the OUT pin and the FLT pin will both output the “L” signal. When the power supply voltage rises to the UVLO OFF voltage, these pins will be reset. However, during the fault output holding time set in “Fault status output” section, the OUT pin and the FLT pin will hold the “L” signal. In addition, to prevent mis-triggers due to noise, mask time $t_{UVLO1FIL}$ and $t_{UVLO2FIL}$ are set on both low and high voltage sides.

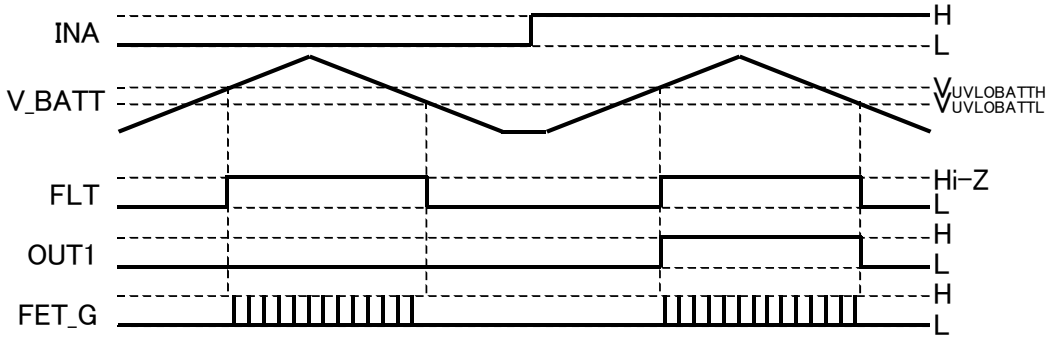


Figure 3. V_BATT UVLO Function Operation Timing Chart

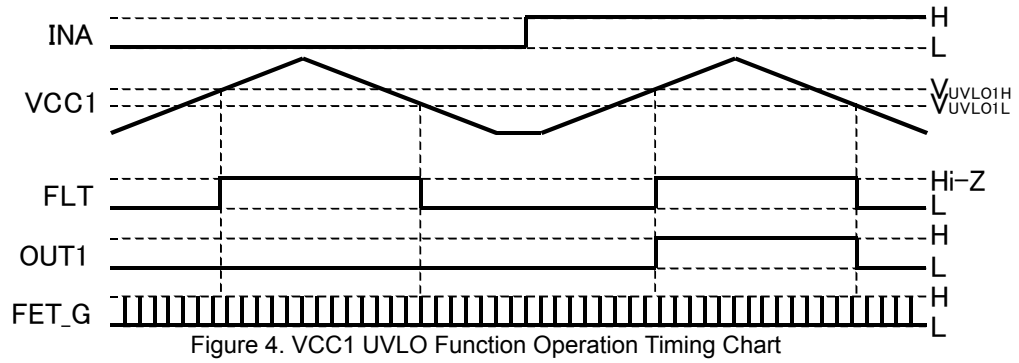


Figure 4. VCC1 UVLO Function Operation Timing Chart

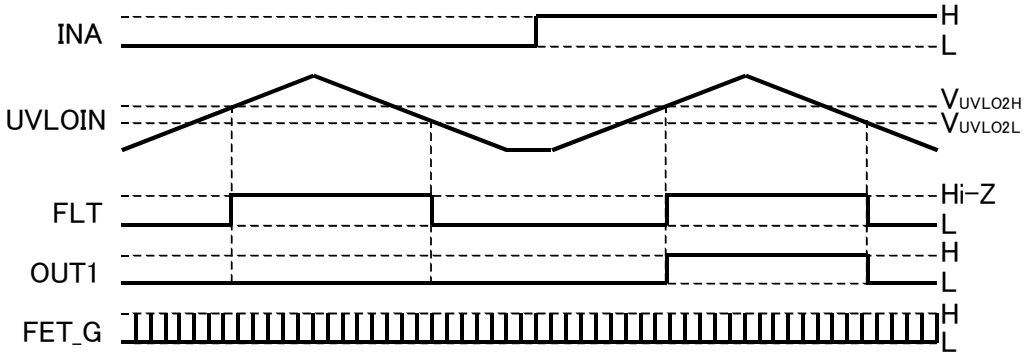


Figure 5. VCC2 UVLO Function Operation Timing Chart

Description of Functions and Examples of Constant Setting - continued

3. Short circuit protection (SCP) function

When the SCPIN pin voltage exceeds a voltage set with the V_{SCDET} parameter, the SCP function will be activated. When the SCP function is activated, the OUT pin voltage will be set to the “Hi-Z” level and the PROOUT pin voltage will go to the “L” level first (soft turn-OFF).Next, when the short-circuit current falls below the threshold value and after t_{SCPOFF} has passed, OUT pin and PROOUT pin become L. Finally, when the fault output holding time is completed, the SCP function will be released.

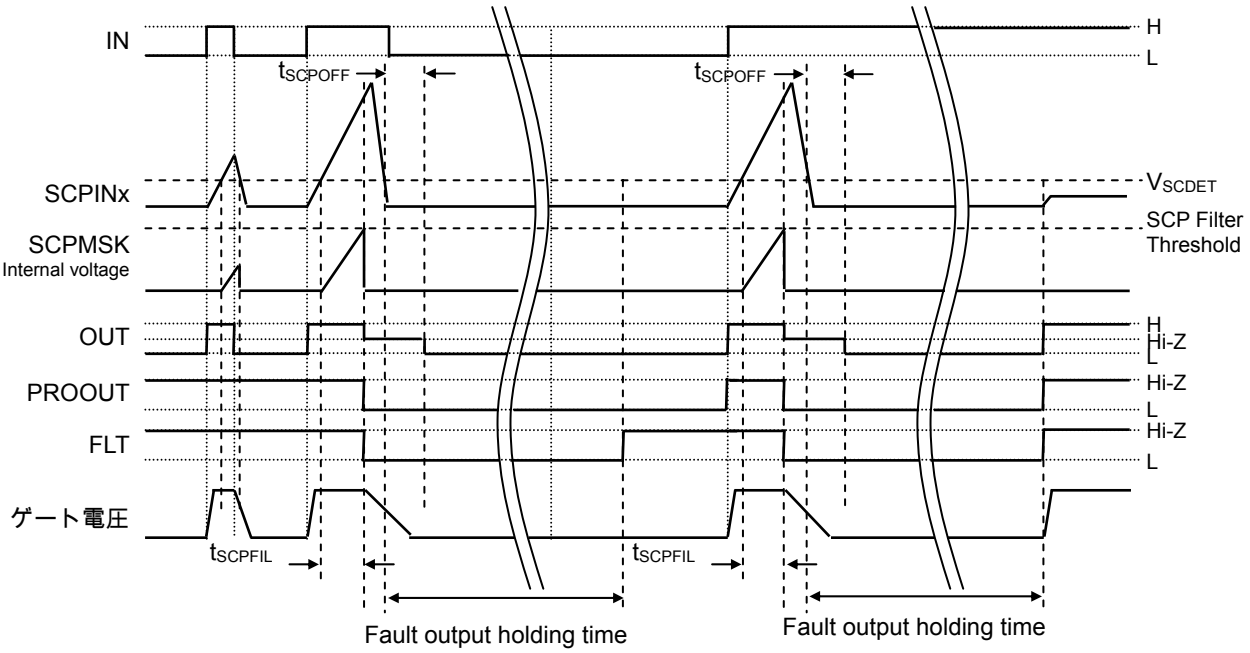


Figure 6. SCP Operation Timing Chart

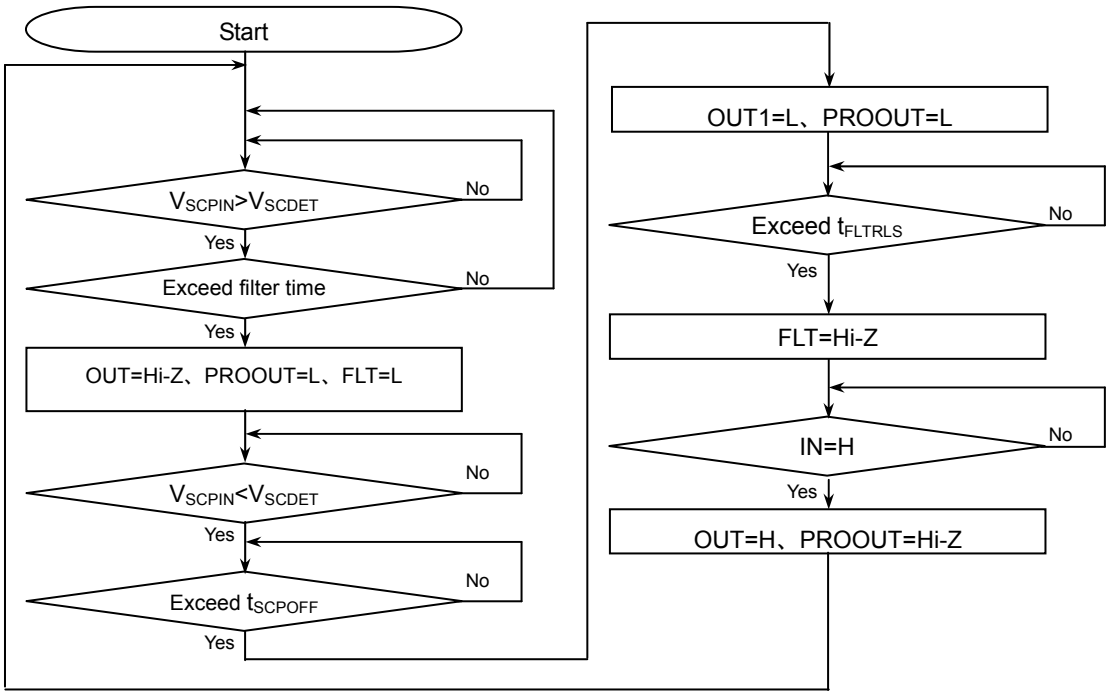


Figure 7. SCP Operation Status Transition Diagram

Description of Functions and Examples of Constant Setting - continued

4. Miller Clamp function

When OUT1=L and PROOUT pin voltage < V_{OUT2ON}, internal MOS of OUT2 pin is turned ON, and miller clamp function operates. While the short-circuit protection function is activated, miller clamp function operates after lapse of soft turn-OFF release time t_{SCPOFF}.

Short current	SCPIN	INA	PROOUT	OUT2
Detected	Not less than V_{SCDET}	X	X	Hi-Z
Not detected	X	L	Not less than V_{OUT2ON}	Hi-Z
	X	L	Not more than V_{OUT2ON}	L
	X	H	X	Hi-Z

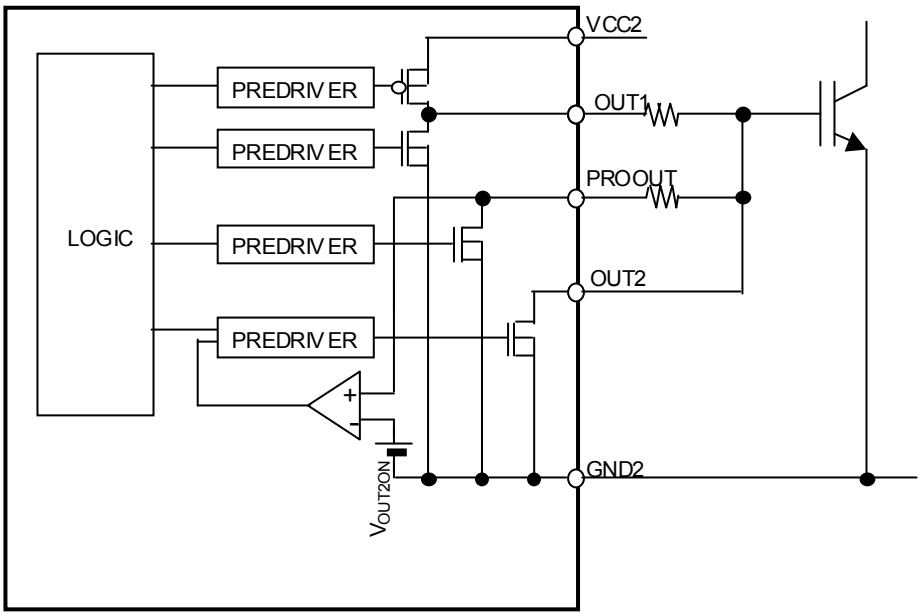


Figure 8. Block Diagram of Miller Clamp Function

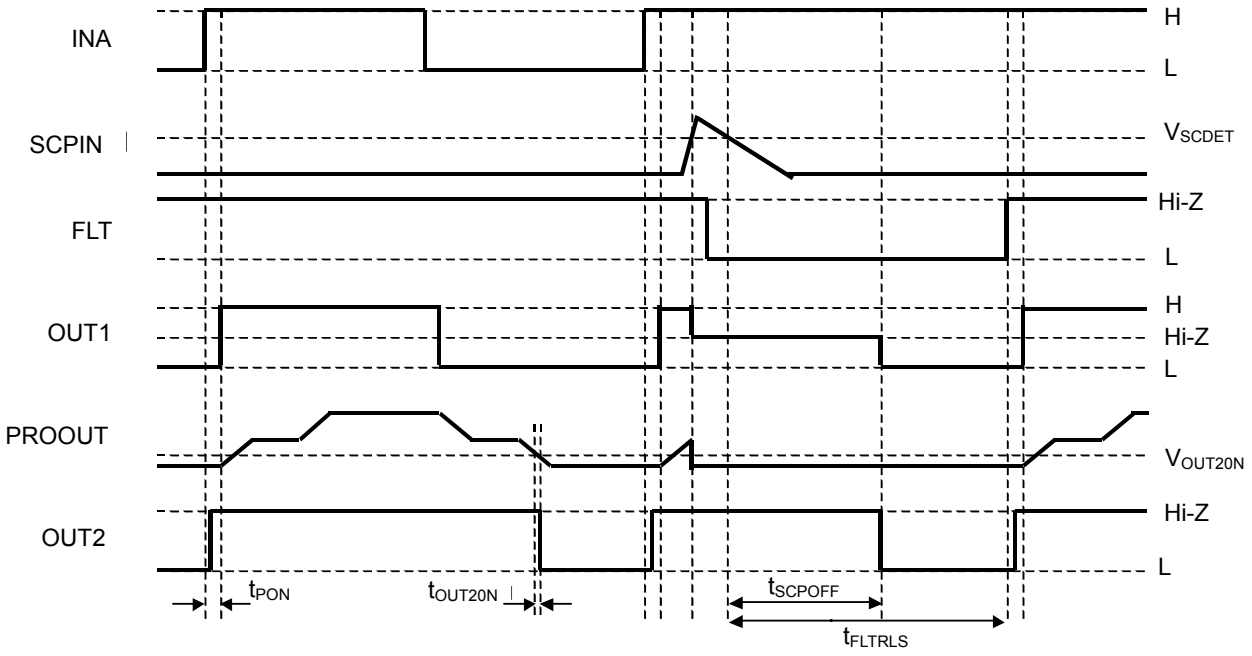


Figure 9. Timing chart of Miller Clamp Function

Description of Functions and Examples of Constant Setting - continued

5. Temperature monitor function

Constant current is supplied from TOx pins from the built-in constant current circuit. This current value can be adjusted in accordance with the resistance value connected between TC and GND2. Furthermore, TO_X pin has voltage input function, and outputs signal of TOx pin voltage converted to Duty from SENSOR pin. When voltage of either one of TO_X pins is no less than disconnect detection voltage V_{TOH}, SENSOR pin outputs L. Therefore, when only one of the TO_X pins is used, connect a resistor between the other TO pins and GND2 to keep pin voltage at no more than V_{TOH}.

$$\text{Constant current value} = \frac{V_{TC} \times 10}{R_{TC}}$$

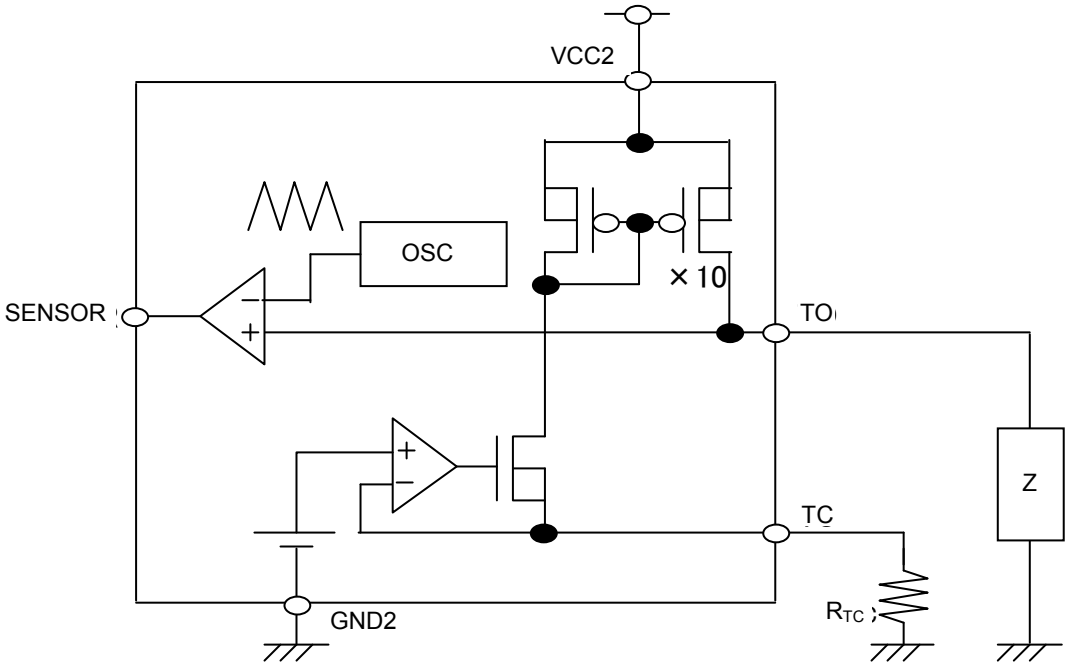
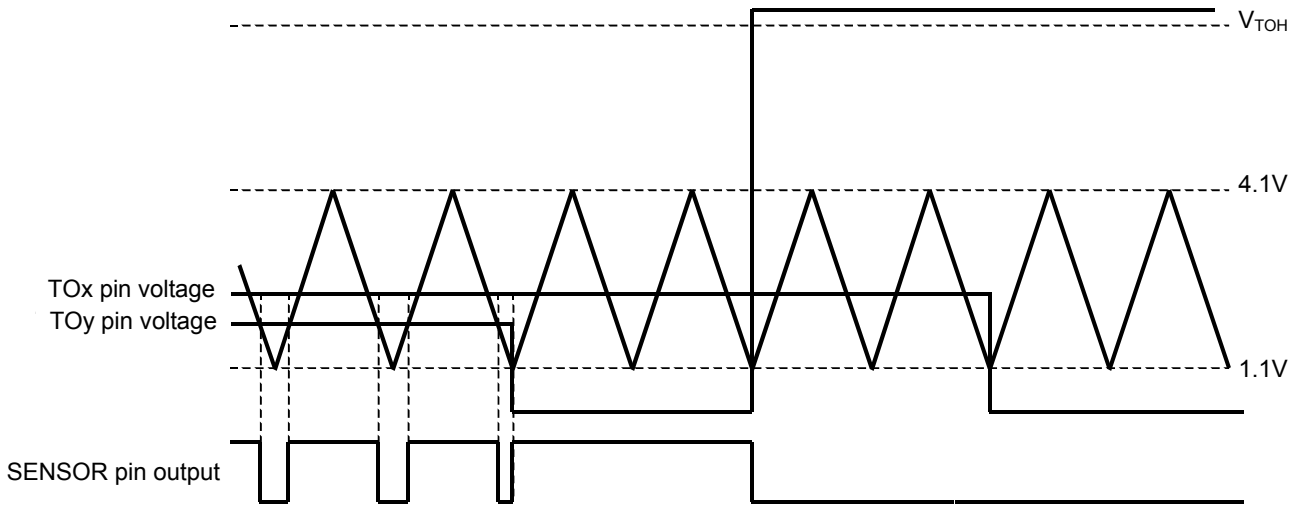


Figure 10. Block Diagram of Temperature Monitor Function



When voltage is no more than V_{TOH}, either one of TO1 and TO2 terminals with lower voltage has precedence.

Figure 11. Timing Chart of Temperature Monitor Function

Description of Functions and Examples of Constant Setting - continued

6. Switching regulator

(1) Basic action

This IC has a built-in switching power supply controller which repeats ON/OFF synchronizing with internal clock. When VBATT voltage is supplied (VBATT > $V_{UVLOBATTH}$), FTE_G pin starts switching by soft-start. Output voltage is determined by the following equation by external resistance and winding ratio "n" of flyback transformer (n= V_{OUT2} side winding number/V_{OUT1} side winding number)

$$V_{OUT2} = V_{FB} \times \{(R_1 + R_2)/R_2\} \times n[V]$$

(2) MAX DUTY

When, for example, output load is large, and voltage level of SENSE pin does not reach current detection level, output is forcibly turned OFF by Maximum On Duty (D_{ONMAX}).

(3) Pinconditions when the switching power supply controller is not used

Implement pin treatment as shown below when switching power supply is not used.

Pin Number	Pin Name	Treatment Method
22	FB	Connect to VCC1
23	COMP	Connect to GND1
24	V_BATT	Connect power supply
25	VREG	Connect capacitor
26	FET_G	No connection
27	SENSE	Connect to VCC1

7. Gate state monitoring function

When gate logic and input logic of output device monitored with PROOUT pin are compared, a logic L is output from OSFB pin when they disaccord. In order to prevent the detection error due to delay of input and output, OSFB filter time t_{OSFBON} is provided.

Description of Functions and Examples of Constant Setting - continued

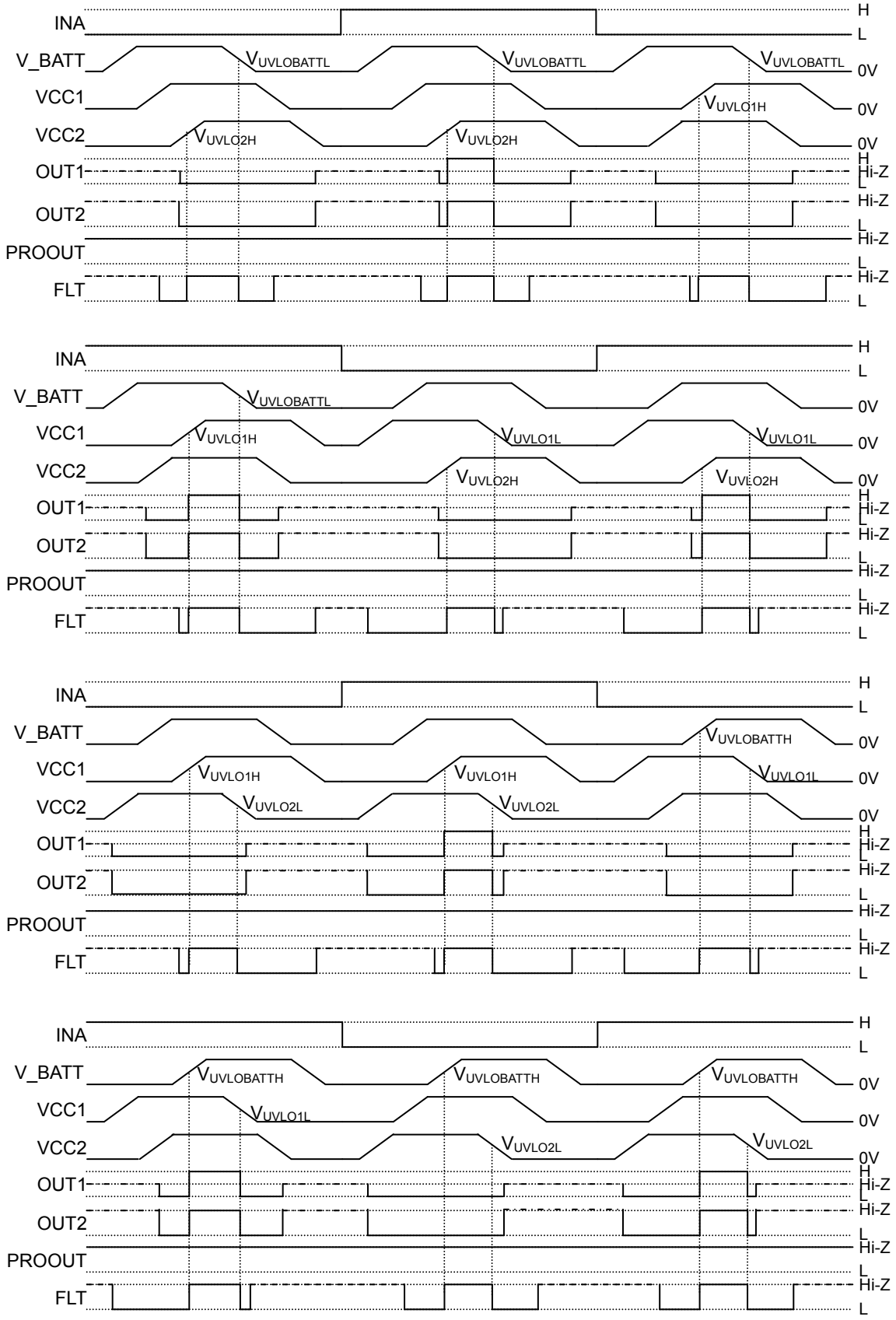
8. I/O condition table

No.	Status	Input							Output				
		VCC1	UVLOIN	VBATT	SCPINx	DIS	INA	PROOUT	OUT1	OUT2	PROOUT	FLT	OSFB
1	SCP	○	H	○	H	L	H	X	Z	Z	L	L	Z
2	VCC1UVLO	UVLO	X	X	L	X	X	H	L	Z	Z	L	Z
3		UVLO	X	X	L	X	X	L	L	L	Z	L	Z
4	VCC2UVLO	X	L	X	L	X	X	H	L	Z	Z	L	Z
5		X	L	X	L	X	X	L	L	L	Z	L	Z
6	VBATT1UVLO	X	X	UVLO	L	X	X	H	L	Z	Z	L	Z
7		X	X	UVLO	L	X	X	L	L	L	Z	L	Z
8	Disable	○	H	○	L	H	X	H	L	Z	Z	Z	L
9		○	H	○	L	H	X	L	L	L	Z	Z	Z
10	Normal Operation L Input	○	H	○	L	L	L	H	L	Z	Z	Z	L
11		○	H	○	L	L	L	L	L	L	Z	Z	Z
12	Normal Operation H Input	○	H	○	L	L	H	H	H	Z	Z	Z	Z
13		○	H	○	L	L	H	L	H	Z	Z	Z	L

○ : VCC1 > UVLO, X: Don't care, Z: Hi-Z

Description of Functions and Examples of Constant Setting - continued

9. Power supply startup / shutoff sequence



: Since the VCC2 to GND2 pin voltage is low and the output MOS does not turn ON, the output pins become Hi-Z conditions.

: Since the VCC1 pin voltage is low and the FLT output MOS does not turn ON, the output pins become Hi-Z conditions.

Figure 12. Power Supply Startup / Shutoff Sequence

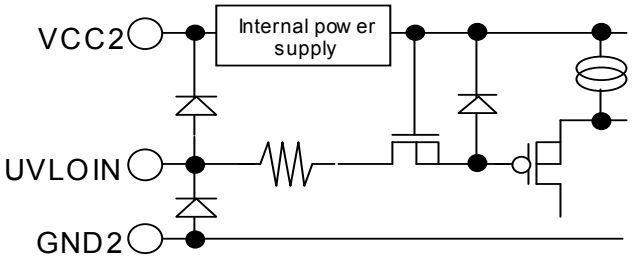
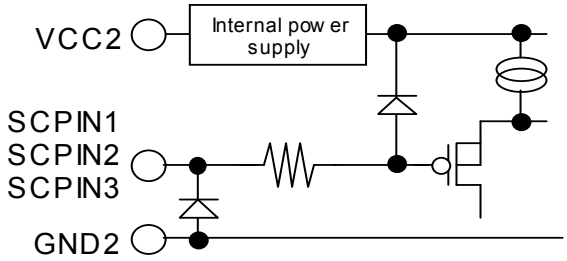
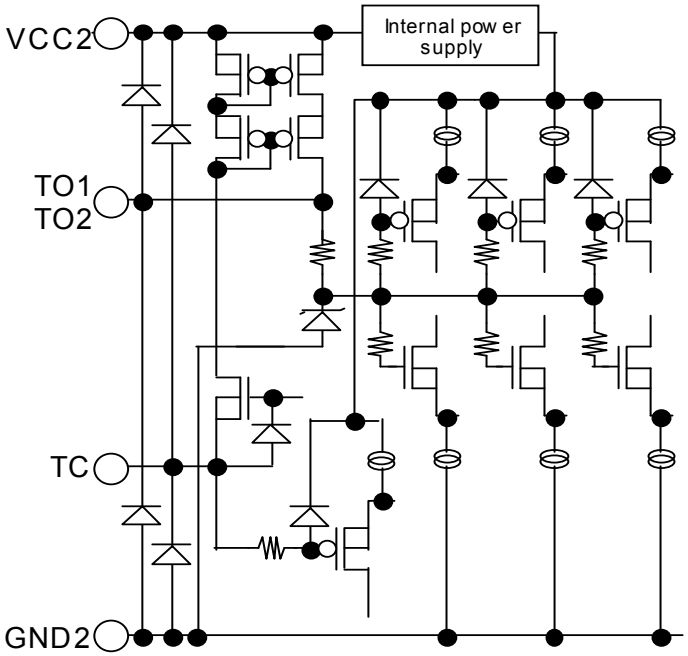
Power Dissipation

Figure 13. SSOP-B28W Derating Curve

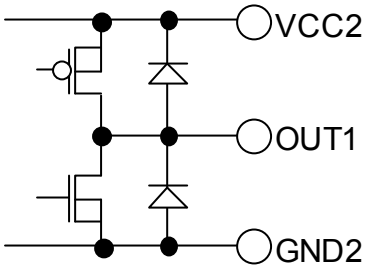
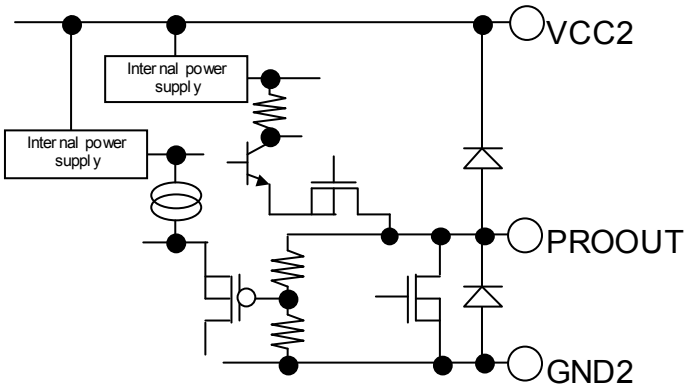
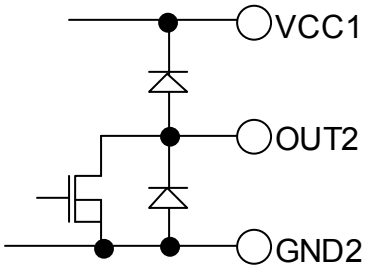
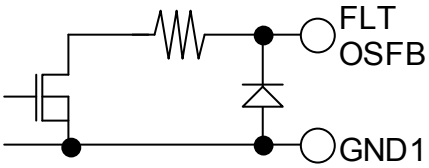
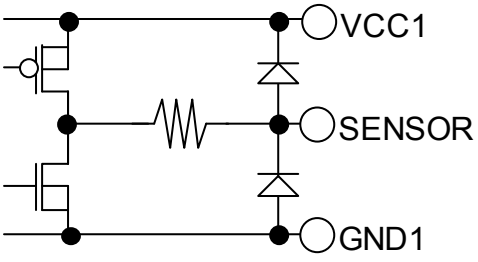
Thermal Design

Please make sure that the IC's chip temperature Tj is not over 150°C, while considering the IC's power consumption (W), package power (Pd) and ambient temperature (Ta). When Tj=150°C is exceeded, the IC may malfunctions or some problems (ex. abnormal operation of various parasitic elements and increasing of leak current) may occur. Constant use under these circumstances leads to deterioration and eventually IC may destruct. Tjmax=150°C must be strictly obeyed under all circumstances.

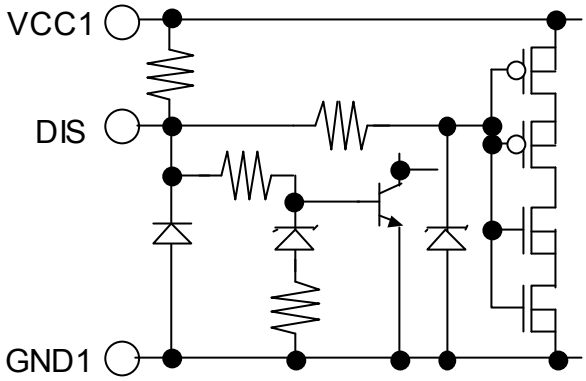
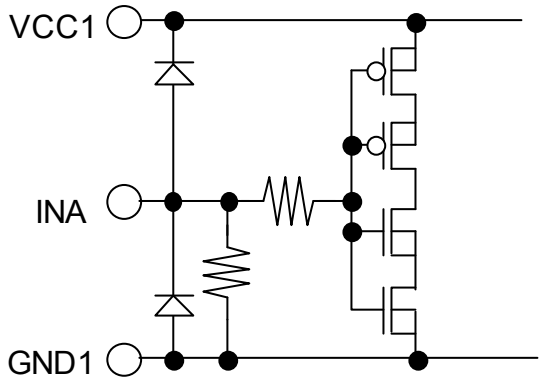
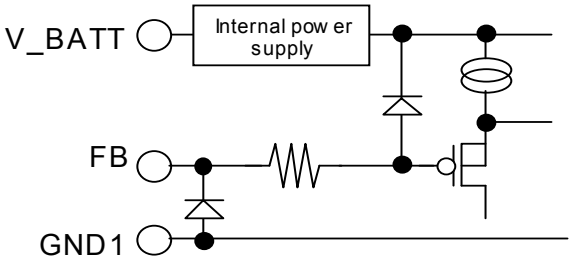
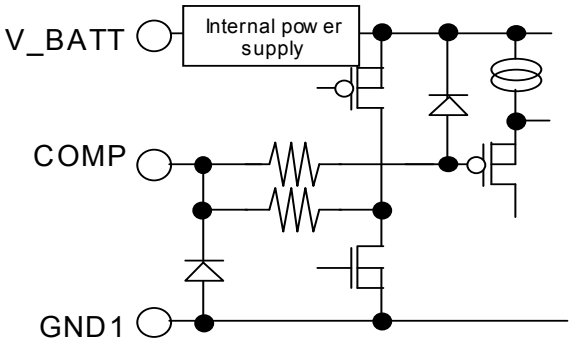
I/O Equivalent Circuit

Pin No.	Pin Name / Pin Function	Input Output Equivalent Circuit Diagram
2	UVLOIN Output-side UVLO setting pin	
3	SCPIN1 Short circuit current detection pin 1	
4	SCPIN2 Short circuit current detection pin 2	
5	SCPIN3 Short circuit current detection pin 3	
6	TO1 Constant current output pin / sensor voltage input pin 1	
7	TO2 Constant current output pin / sensor voltage input pin 2	
8	TC Constant current setting resistor connection pin	

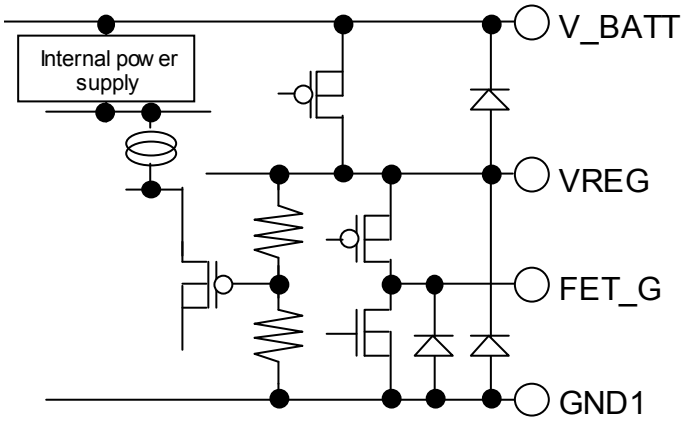
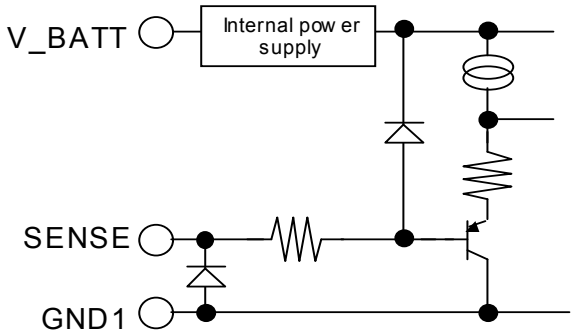
I/O Equivalent Circuit - continued

Pin No.	Pin Name / Pin Function	Input Output Equivalent Circuit Diagram
11	OUT1 Output pin	
9	PROOUT Soft turn-OFF pin /Gate voltage input pin	
13	OUT2 Output pin for Miller Clamp	
16	FLT Fault output pin	
19	OSFB Output state feedback output pin	
20	SENSOR Temperature information output pin	

I/O Equivalent Circuit - continued

Pin No.	Pin Name Pin Function	Input Output Equivalent Circuit Diagram
17	DIS Input enabling signal input pin	
18	INA Control input pin	
22	FB Error amplifier inverting input pin for switching controller	
23	COMP Error amplifier output pin for switching controller	

I/O Equivalent Circuit - continued

Pin No.	Pin Name / Pin Function	Input Output Equivalent Circuit Diagram
25	VREG Power supply pin for driving MOS FET of switching controller	
26	FET_G MOS FET control pin for switching controller	
27	SENSE Current feedback resistor connection pin for switching controller	

Operational Notes

1. Reverse Connection of Power Supply
   Connecting the power supply in reverse polarity can damage IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply terminals.

2. Power Supply Lines
   Design PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage
   Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern
   When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration
   Should by any chance the power dissipation rating be exceeded, the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions
   These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Inrush Current
   When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field
   Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards
   When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors
    Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

11. Unused Input Terminals
    Input terminals of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input terminals should be connected to the power supply or ground line.

Operational Notes – continued

12. Regarding Input Pins of the IC
    This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

    When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.
    When GND > Pin B, the P-N junction operates as a parasitic transistor.

    Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

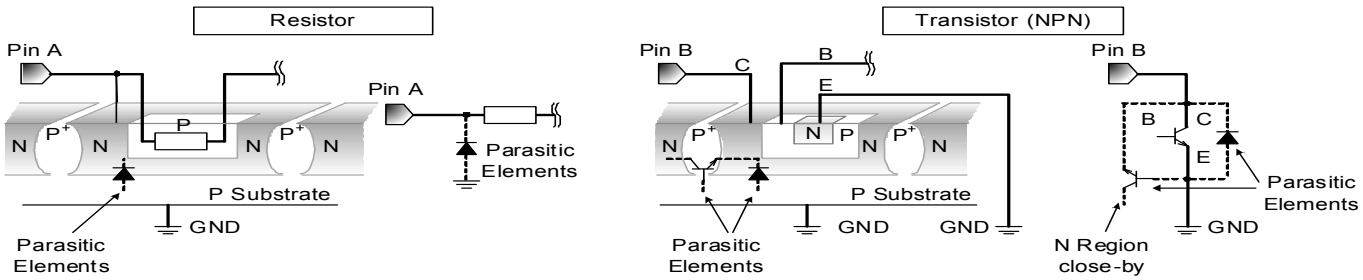


Figure 14. Example of monolithic IC structure

13. Ceramic Capacitor
    When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

Revision History

Date	Revision	Changes
13.Jul.2012	Tentative 001	New Release (Only Japanese version)
14.Jul.2012	Tentative 002	
28.Feb.2013	Tentative 003	
19.Mar.2013	Tentative 004	
1.Apr.2013	Tentative 005	
5.Jul.2013	Tentative 006	
18.Oct.2013	Tentative 007	English version new release
18.Oct.2013	Tentative 008	Correcting mistakes